

isc Silicon PNP Power Transistor

2SA1040

DESCRIPTION

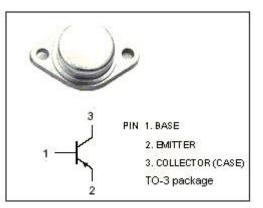
- High Current Capability
- · Good Linearity of hFE
- Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= -120V(Min.)
- Complement to Type 2SC2430
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

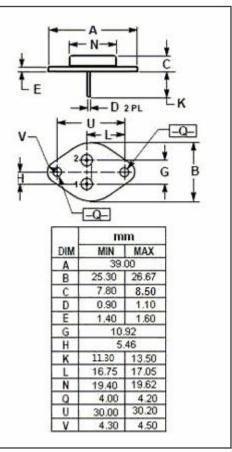
APPLICATIONS

• Designed for power switching , high frequency power amplifer, switching regulator and DC/DC converters.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|--|---------|------|
| V _{CBO} | Collector-Base Voltage | -120 | V |
| V _{CEO} | Collector-Emitter Voltage | -120 | V |
| V _{EBO} | Emitter-Base Voltage | -5 | V |
| lc | Collector Current-Continuous | -10 | A |
| Pc | Collector Power Dissipation @T _c =25°C | 100 | W |
| Tj | Junction Temperature | 175 | Ĉ |
| T _{stg} | Storage Temperature | -55~175 | °C |





isc website: <u>www.iscsemi.com</u>



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ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | МАХ | UNIT |
|----------------------|--------------------------------------|---|------|------|------|------|
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | I _C = -30mA; I _B = 0 | -120 | | | V |
| V _{(BR)CBO} | Collector-Base Breakdown Voltage | I _C = -1mA; I _E = 0 | -120 | | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | I _E = -1mA; I _C = 0 | -5 | | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = -5A; I _B = -0.5A | | | -1.2 | V |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | Ic= -5A; I _B = -0.5A | | | -1.8 | V |
| І _{сво} | Collector Cutoff Current | V _{CB} = -120V; I _E = 0 | | | -50 | μA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = -5V; I _C = 0 | | | -50 | μA |
| h _{FE} | DC Current Gain | I _C = -1A; V _{CE} = -5V | 35 | | 200 | |
| C _{OB} | Output Capacitance | I _E = 0; V _{CB} = -10V; f= 1.0MHz | | 400 | | pF |
| f⊤ | Current-Gain—Bandwidth Product | I _C = -1A; V _{CE} = -10V | | 60 | | MHz |

Notice:

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